

SURFACE MOUNT PLASTIC SILICON RECTIFIERS

REVERSE VOLTAGE - 50 to 1000Volts
POWER CURRENT - 1.0 Amperes

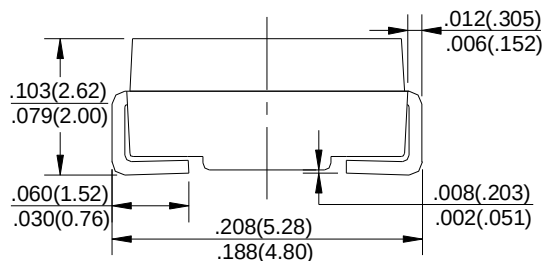
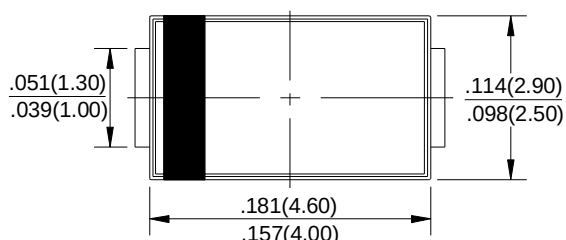
FEATURES

- Diffused junction
- For surface mounted applications
- Low reverse leakage current
- Low forward voltage drop
- High current capability
- Plastic material has UL flammability classification 94V-0

MECHANICAL DATA

- Case: Molded Plastic
- Polarity: Indicated by cathode band
- Weight: 0.002 ounces, 0.053 grams
- Mounting position: Any

A-SMA



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	M1A	M2A	M3A	M4A	M5A	M6A	M7A	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @T _L =100 °C	I <sub(av)< sub=""></sub(av)<>	1.0							A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed On Rated Load (JEDEC Method)	I _{FSM}	30							A
Maximum Forward Voltage at 1.0A DC	V _F	1.1							V
Maximum DC Reverse Current @T _J =25°C at Rated DC Blocking Voltage @T _J =100°C	I _R	5.0 100							uA
Typical Junction Capacitance (Note1)	C _J	10							pF
Typical Thermal Resistance (Note2)	R _{θJC}	30							°C/W
Operating Temperature Range	T _J	-55 to +125							°C
Storage Temperature Range	T _{STG}	-55 to +125							°C

NOTES:1.Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

2.Thermal resistance junction to lead.



FIG. 1 - FORWARD CURRENT DERATING CURVE

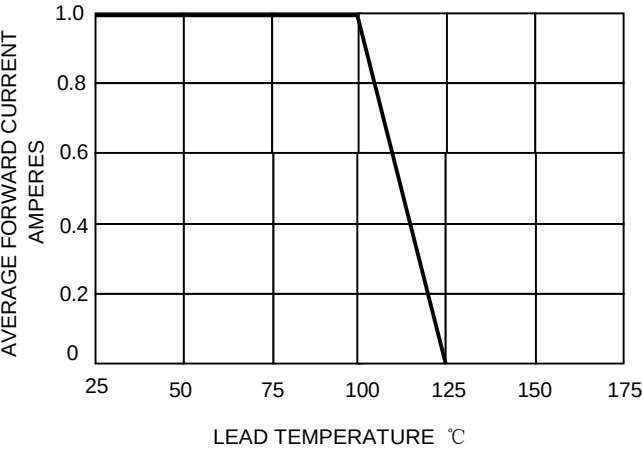
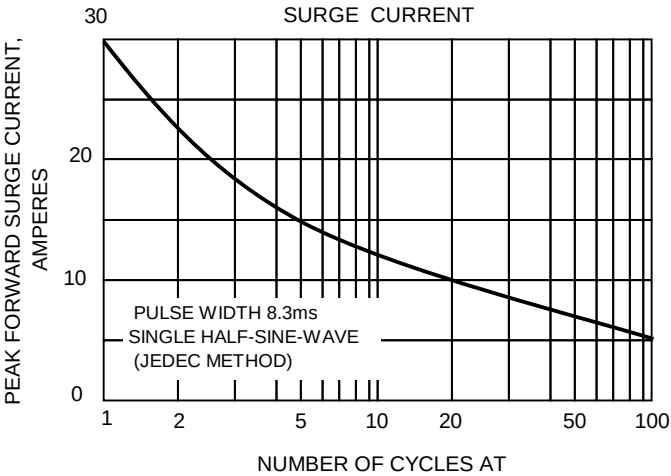


FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT



SINGLE PHASE HALF WAVE 60Hz
RESISTIVE OR INDUCTIVE LOAD

FIG.3-TYPICAL FORWARD CHARACTERISTICS

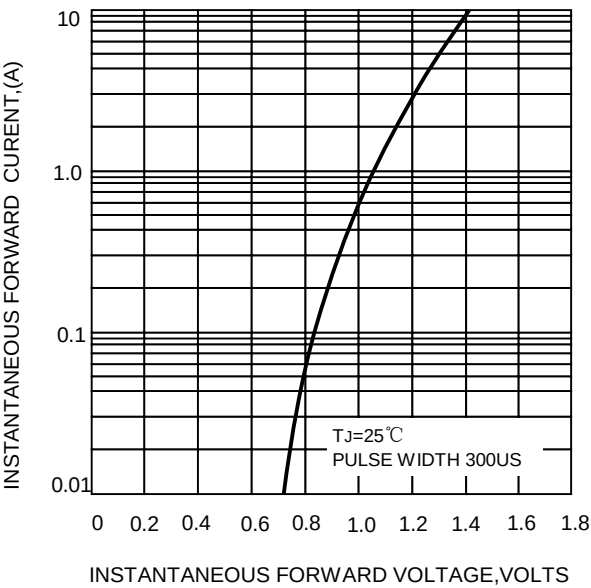


FIG.4-TYPICAL REVERSE CHARACTERISTICS

